

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
S2	5	(mram (magnet\$2 near2 memory)) and ((writ\$3 near5 current near5 control\$4 near5 line) same (shar\$3 near3 (bitline (bit adj line) digitline (digit adj line) row)))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2003/10/02 20:37
S1	96	(mram (magnet\$2 near2 memory)) and (writ\$3 near5 current near5 control\$4 near5 line)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2003/10/02 20:37
S4	37	((mram (magnet\$2 near2 memory)) and (writ\$3 with current with control\$4)) and (shar\$3 near3 (bitline (bit adj line) digitline (digit adj line) row))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2003/10/02 20:38
S3	544	(mram (magnet\$2 near2 memory)) and (writ\$3 with current with control\$4)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2003/10/02 20:39
S5	272	(mram (magnet\$2 near2 memory)) and (writ\$3 with current with control\$4 with (line circuit))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2003/10/02 20:40
S7	2	(mram (magnet\$2 near2 memory)) and ((writ\$3 near3 current near3 control\$4 with (line circuit)) same (shar\$3 near3 (bitline (bit adj line) digitline (digit adj line) row)))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2003/10/02 21:29
S6	7	(mram (magnet\$2 near2 memory)) and ((writ\$3 with current with control\$4 with (line circuit)) same (shar\$3 near3 (bitline (bit adj line) digitline (digit adj line) row)))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2003/10/02 21:29
S10	2617	365/158.ccls. 365/171.ccls. 365/172.ccls. 365/173.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/24 18:15
S9	2280	365/158.ccls. 365/171.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/24 18:15

S8	2	10/170,580	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/24 18:17
S15	15	S13 and S14	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/24 18:25
S16	155	S10 and (writ\$3 adj3 driver) and (bitline digitline (bit adj line) (digit adj line)) and (wordline (word adj line) row) and (array block bank)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/24 18:26
S18	48	S16 and ((column bitline digitline (bit adj line) (digit adj line)) with shar\$3 with (block bank array))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/24 18:28
S19	276	(mram (magnetic adj3 (memory ram))) and (writ\$3 adj3 (bitline digitline (bit adj line) (digit adj line))) and (column near3 select\$3 near3 line)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/24 18:36
S21	152	S20 and (block bank array)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/24 18:37
S20	152	S19 and (writ\$3 adj3 driver)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/24 18:37
S14	23	S10 and (writ\$3 adj3 (bitline digitline (bit adj line) (digit adj line))) and ((column near3 select\$3 near3 line) with shar\$3)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/24 18:37

S13	108	S12 and (block bank array)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/24 18:37
S12	108	S11 and (writ\$3 adj3 driver)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/24 18:37
S11	174	S10 and (writ\$3 adj3 (bitline digitline (bit adj line) (digit adj line))) and (column near3 select\$3 near3 line)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/24 18:37
S22	18	S21 and (writ\$3 adj3 (bitline digitline (bit adj line) (digit adj line))) and ((column near3 select\$3 near3 line) with shar\$3)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/24 18:38
S23	673	S10 and (writ\$3 adj3 line) and (block bank array)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/24 18:39
S24	552	S23 not (mitsubishi Renesas).as.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/24 18:40
S17	21	S16 and ((column bitline digitline (bit adj line) (digit adj line)) near3 shar\$3 near3 (block bank array))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/24 18:40
S25	11	S24 and ((column bitline digitline (bit adj line) (digit adj line)) near3 shar\$3 near3 (block bank array))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/24 18:57

S26	33	S10 and ((column bitline digitline (bit adj line) (digit adj line)) near3 shar\$3 near3 (block bank array))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/25 12:48
S28	2576	(365/158 365/171 365/173).ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/25 12:51
S29	95	S27 and S28	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/25 12:57
S27	7083	(365/230.03 365/230.06 365/230.07 365/231 365/232).ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/14 20:09
L3	185	L1 and L2	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/14 20:09
L2	2775	(365/158 365/171 365/173).ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/14 20:09
L1	7591	(365/230.03 365/230.06 365/230.07 365/231 365/232 365/66).ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/14 20:09
L11	157	((mram (magnet\$2 near2 memory)) and (writ\$3 with current with control\$4)) and (shar\$3 near3 (bitline (bit adj line) digitline (digit adj line) row))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/14 20:10

L10	16	(mram (magnet\$2 near2 memory)) and ((writ\$3 with current with control\$4 with (line circuit)) same (shar\$3 near3 (bitline (bit adj line) digitline (digit adj line) row)))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/14 20:10
L9	4	(mram (magnet\$2 near2 memory)) and ((writ\$3 near3 current near3 control\$4 with (line circuit)) same (shar\$3 near3 (bitline (bit adj line) digitline (digit adj line) row)))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/14 20:10
L8	2	10/170,580	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/14 20:10
L7	14	L6 and ((column bitline digitline (bit adj line) (digit adj line)) near3 shar\$3 near3 (block bank array))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/14 20:10
L6	629	L5 not (mitsubishi Renesas).as.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/14 20:10
L5	764	L4 and (writ\$3 adj3 line) and (block bank array)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/14 20:10
L4	2824	365/158.ccls. 365/171.ccls. 365/172.ccls. 365/173.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/14 20:10
L12	11	(mram (magnet\$2 near2 memory)) and ((writ\$3 near5 current near5 control\$4 near5 line) same (shar\$3 near3 (bitline (bit adj line) digitline (digit adj line) row)))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/14 20:11

L13	3	((thin adj3 film) and (magnetic mram) and (array block bank) and resistance and (write adj3 (bitline digitline (bit adj line) (digit adj line))) and (divid\$3 partition\$3 section\$4) and ((column near3 select\$3 near3 line) near3 shar\$3) and (write adj3 driver)).clm.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/14 20:14
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